🔉 ovaga

IRFR3607PBF

Data Sheet

75V Single N-Channel HEXFET Power MOSFET in a D-Pak package; A IRFR3607P.	BF
with Standard Packaging	

Manufacturers	Infineon Technologies Corporation	
Package/Case	TO-252	anana
Product Type	Transistors	6-64.64
RoHS	Green	
Lifecycle		Images are for reference only

Please submit RFQ for IRFR3607PBF or Email to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

General Description

The IR MOSFET family of power MOSFETs utilizes proven silicon processes offering designers a wide portfolio of devices to support various applications such as DC motors, inverters, SMPS, lighting, load switches as well as battery powered applications. The devices are available in a variety of surface mount and through-hole packages with industry standard footprints for ease of design.

Planar cell structure for wide SOA

Optimized for broadest availability from distribution partners

Product qualification according to JEDEC standard

Silicon optimized for applications switching below <100kHz

Industry standard surface mount package

Increased ruggedness

Wide availability from distribution partners

Industry standard qualification level

High performance in low frequency applications

Standard pinout allows for drop in replacement

Features

Optimized for broadest availability from distribution partners Product qualification according to JEDEC standard Normal level : Optimized for 10 V gate drive voltage Industry standard surface-mount power package Capable of being wave-soldered





Related Products



IRLTS6342TRPBF

Infineon Technologies Corporation TSOP-6



IRF9310PBF Infineon Technologies Corporation SOIC-8



IRF9358TRPBF Infineon Technologies Corporation SOP-8



IRFB3307ZPBF Infineon Technologies Corporation TO-220AB







IRLHS6376TRPBF

Infineon Technologies Corporation PQFN2x2DD

IRFH9310TRPBF

Infineon Technologies Corporation PQFN-8

IRFB7430PBF

Infineon Technologies Corporation TO-220

IRF7351TRPBF

Infineon Technologies Corporation SOIC-8